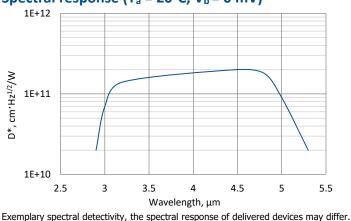


PVI-2TE-5-1×1-T08-wAl₂O₃-36

2.9 – 5.5 µm HgCdTe two-stage thermoelectrically cooled, optically immersed photovoltaic detector

PVI-2TE-5-1×1-TO8-wAl₂O₃-36 is two-stage thermoelectrically cooled IR photovoltaic detector based on sophisticated HgCdTe heterostructure for the best performance and stability. The device is optimized for the maximum performance at 5 µm. Detector element is monolithically integrated with hyperhemispherical GaAs microlens in order to improve performance of the device. Reverse bias may significantly increase response speed and dynamic range. It also results in improved performance at high frequencies, but 1/f noise that appears in biased devices may reduce performance at low frequencies. 3° wedged sapphire (wAl₂O₃) window prevents unwanted interference effects.

Spectral response ($T_a = 20^{\circ}C$, $V_b = 0$ mV)





Specification ($T_a = 20$ °C, $V_b = 0$ mV)

Parameter	Detector type
	PVI-2TE-5-1×1-TO8-wAl ₂ O ₃ -36
Active element material	epitaxial HgCdTe heterostructure
Cut-on wavelength $\lambda_{\text{cut-on}}$ (10%), μ m	2.9±1.0
Peak wavelength λ _{peak} , μm	4.2±0.5
Optimum wavelength λ _{opt} , μm	5.0
Cut-off wavelength $\lambda_{\text{cut-off}}$ (10%), μ m	5.5±0.3
Detectivity D*(λ _{peak}), cm·Hz ^{1/2} /W	≥2.0×10 ¹¹
Detectivity D*(λ_{opt}), cm·Hz ^{1/2} /W	≥9.0×10 ¹⁰
Current responsivity R _i (λ _{peak}), A/W	≥2.0
Current responsivity $R_i(\lambda_{opt})$, A/W	≥1.3
Time constant τ, ns	≤80
Resistance R, Ω	≥1000
Active element temperature T _{det} , K	~230
Optical area A _o , mm×mm	1×1
Package	TO8
Acceptance angle Φ	~36°
Window	wAl ₂ O ₃



- High performance
- D* better by one order of magnitude compared with the same type uncooled detector
- Wide dynamic range
- Quantity discounted price
- Fast delivery

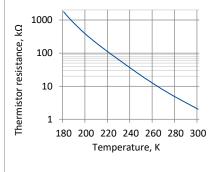
Applications

- Contactless temperature measurements (railway transport, industrial and laboratory processes monitoring)
- Flame and explosion detection
- Threat warning systems
- Gas detection, monitoring and analysis (CO, CO₂, NO_v)
- In-vivo alcohol detection
- Breath analysis
- Solids analysis
- Leakage control in gas pipelines
- Combustion process control

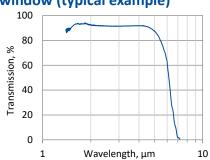
Two-stage thermoelectric cooler parameters

Parameter	Value
T _{det} , K	~230
V _{max} , V	1.3
I _{max} , A	1.2
O _{max} , W	0.36

Thermistor characteristics

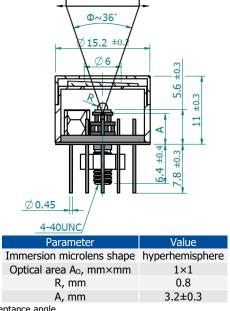


Spectral transmission of wAl₂O₃ window (typical example)





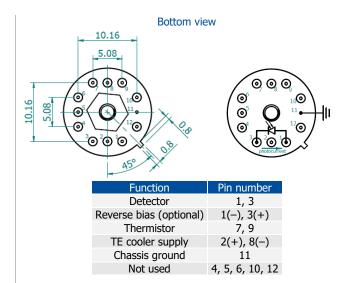






A – distance from the bottom of the 2TE-TO8 header to the focal plane

R – hyperhemisphere microlens radius



Precautions for use and storage

- Standard ohmmeter may overbias and damage the detector. Bias of 10 mV can be used for resistance measurements.
- Heatsink with thermal resistance of ~2 K/W is necessary to dissipate heat generated by 2TE cooler.
- Operation in 10% to 80% humidity and -20°C to 30°C ambient temperature.
- Beam power limitations for optically immersed detector:
 - irradiance with CW or single pulse longer than 1 μs irradiance on the apparent optical active area must not exceed 2.5 W/cm².
 - irradiance of the pulse shorter than 1 µs must not exceed 10 kW/cm².
- Storage in dark place with 10% to 90% humidity and -20°C to 50°C ambient temperature.

X-ON Electronics

Largest Supplier of Electrical and Electronic Components

Click to view similar products for Photoelectric Sensors category:

Click to view products by Vigo System manufacturer:

Other Similar products are found below:

7442AD2X5FRX EX-19B-LP EX-19SB-PN 7443AR0X5FRX 7452AD4D4NNX 7694ADE04DS2X FE7C-FRC6S-M FX-305 PM-R24-R
Q45VR2FPQ 13104RQD07 E3JUXM4MN E3L2DC4 E3S3LE21 E3SCT11M1J03M E3SDS20E21 E3VDS70C43S E3XNM16 BR23P
HOA6563-001 OJ-3307-30N8 OS-311A-30 P32013 P34036 P43004 P60001 PB10CNT15PO S14132 935286-000 S52101 S56258 FDSN500 FE7B-FDRB6-M SU-79 T36342 T40300 T60001 PD60CNX20BP FX-302-HY FZS PM-T64W PZ2-51P CX-491-P-J CYNUTX10
UZB802 UZB803 UZFRG1 UZFRG4 UZFRT4 UZFTT8